

#### SSC8122GS7

### N-Channel Enhancement Mode MOSFET with ESD Protection

#### > Features

VDS	VGS	RDSON Typ.	ID	ESD
		220mR@4V5		
20V	±8V	300mR@2V5	1.5A	2K
		460mR@1V8		

## Description

This device is a N-Channel enhancement mode MOSFET which is produced with high cell density and DMOS trench technology. This device particularly suits low voltage applications, especially for battery powered circuits, the tiny and thin outline saves PCB consumption.

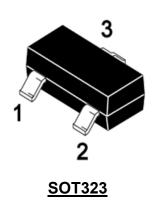
## > Applications

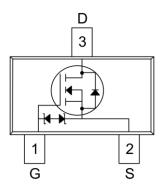
- Replace Digital Transistor
- Battery Operated Systems
- Power Supply Converter Circuits
- Load/Power Switching cellPhones

### Ordering Information

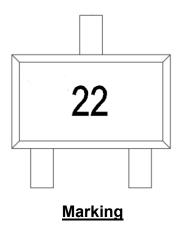
Device	Package	Shipping
SSC8122GS7	SOT323	3000/Reel

## Pin configuration





## Pin Configuration (Top View)





# ➤ Absolute Maximum Ratings(T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
V <sub>DSS</sub>	Drain-to-Source Voltage	20	V
V <sub>GSS</sub>	Gate-to-Source Voltage	±8	V
I <sub>D</sub>	Continuous Drain Current <sup>a</sup>	1.5	Α
I <sub>DM</sub>	Pulsed Drain Current <sup>b</sup>	4.5	Α
P <sub>D</sub>	Power Dissipation <sup>c</sup>	0.46	W
P <sub>DSM</sub>	Power Dissipation <sup>a</sup>	0.25	W
TJ	Operation junction temperature	-55 to 150	°C
T <sub>STG</sub>	Storage temperature range	-55 to 150	°C

# ➤ Thermal Resistance Ratings(T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Typical	Maximum	Unit
R <sub>0JA</sub>	Junction-to-Ambient Thermal Resistance <sup>a</sup>		500	°C/W
R <sub>0JC</sub>	Junction-to-Case Thermal Resistance		270	C/VV

#### Note:

- a. The value of RθJA is measured with the device mounted on 1 in² FR-4 board with 2oz.copper,in a still air environment with TA=25°C. The value in any given application depends on the user is specific board design. The current rating is based on the t≤ 10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation PD is based on TJ(MAX)=150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

SSC-V2.3 <u>www.sscsemi.com</u> Analog Future

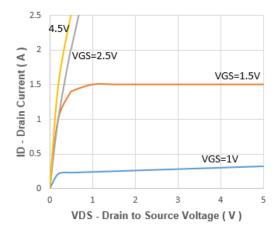


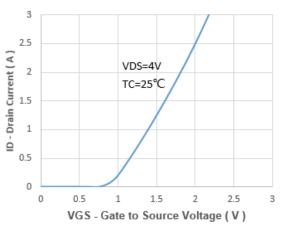
# ➤ Electronics Characteristics(T<sub>A</sub>=25 °C unless otherwise noted)

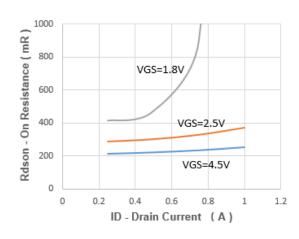
Symbol	Parameter	Test Conditions	Min	Тур.	Max	Unit
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	VGS=0V,ID=250uA	20			V
V <sub>GS (th)</sub>	Gate Threshold Voltage	VDS=VGS,ID=250uA	0.5	0.8	1.2	V
	Davis Occurs Oc	VGS=4.5V,ID=0.55A		220	400	
R <sub>DS(on)</sub>	Drain-Source On- Resistance	VGS=2.5V,ID=0.45A		300	500	mR
	Resistance	VGS=1.8V,ID=0.35A		460	800	
I <sub>DSS</sub>	Zero Gate Voltage  Drain Current	VDS=16V,VGS=0V			1	uA
I <sub>GSS</sub>	Gate-Source leak	VGS=±8V,VDS=0V			±10	uA
G <sub>FS</sub>	Forward Transconductance	VDS=5V,ID=0.45A		1.8		S
V <sub>SD</sub>	Forward Voltage	VGS=0V,IS=0.5A			1.3	<b>V</b>
Ciss	Input Capacitance			56		
Coss	Output Capacitance	VDS=10V, VGS=0V, f=100KHZ		15		pF
Crss	Reverse Transfer Capacitance			9		
T <sub>D(ON)</sub>	Turn-on delay time	VGS=4.5V,		22		n
T <sub>D(OFF)</sub>	Turn-off delay time	VDD=10V, RG=6R, ID=0.55A		36		ns

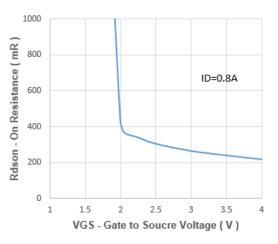


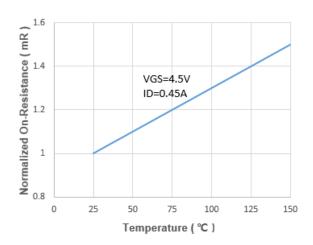
# > Typical Characteristics(T<sub>A</sub>=25°C unless otherwise noted)







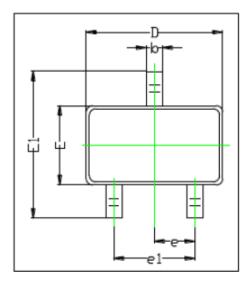




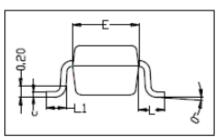


# Package Information

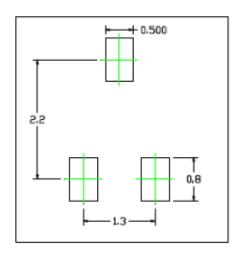
# TOP VIEW



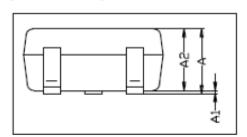
# SIDE VIEW



## SOLDERING PATTERN



## FRONT VIEW



SYMBOL	DIMENSIONS II	N MILLIMETER	
3 TWIDOL	MIN	MAX	
Α	0.900	1.000	
A1	0.00	0.100	
A2	0.900	1.000	
Ь	0.200	0.400	
С	0.080	0.150	
D	2.000	2.200	
E	1.150	1.350	
E1	2.150	2.450	
е	0.650 TYP.		
e1	1.200	1.400	
L	0.525 REF.		
L1	0.260	0.460	
θ	0.	8°	



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